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Construction of a crossed-layer-structure MoS₂/g-C₃N₄ heterojunction with enhanced photocatalytic performance†

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A novel crossed-layer-structure MoS₂/g-C₃N₄ (graphitic carbon nitride) was synthesized by a facile method, and was characterized by a collection of analytical techniques: X-ray diffraction patterns, FT-IR spectra, SEM, TEM, and XPS. The crossed-layer-structure morphologies of MoS₂/g-C₃N₄ could be readily tailored by adjusting the molar ratio of MoS₂ to dicyandiamide; with an increase in the molar ratio from 0.08% to 4%, a morphology transformation was observed. It can be used as a photocatalyst in degrading methyl orange under simulated solar light irradiation. These MoS₂/g-C₃N₄ samples demonstrated 2 to 3 times higher performance than pure g-C₃N₄. We also found that the highest phenol degradation activity was with MoS₂/g-C₃N₄-4 under visible light. The high performance was attributed to the unique morphology that provided low recombination losses of photogenerated charges.

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1. Introduction

Due to the global energy crisis and environmental pollution,^{1–5} various technologies have been used to cope with the crisis. Photocatalysis is considered to be one of the most promising technologies to produce renewable fuels and remove pollutants *via* solar energy. Photocatalytic degradation of pollutants in water by using semiconductor catalysts has received extensive and increasing attention in the past few decades, and various kinds of catalyst suitable for use in natural light have been developed.^{6,7}

The key to achieving solar pollution degradation is to develop stable, efficient, nontoxic and inexpensive photocatalysts that are capable of working in the visible light, which occupies *ca.* 50% of the incoming solar irradiation on earth. In the last few years, a graphite-like organic polymeric carbon nitride (g-C₃N₄), a metal-free photoactive semiconductor consisting of abundant and nontoxic elements, has ignited increasing interest owing to its photocatalytic activity for degradation of pollutants in water under visible-light irradiation, and its cheap, stable, environmental friendly, metal-free features. In fact, g-C₃N₄, one of the oldest synthetic polymers, can be traced back to 1834, and reported for the first time by Liebig and named “melon”.⁸ Unlike graphite, g-C₃N₄ is a semiconductor material with an optical band gap of 2.7 eV.⁹

Recently, g-C₃N₄ derivatives with various heteroatom dopants (*e.g.* C, B, F, S, P, O, I),^{10–17} have been fabricated by co-thermal condensation of suitable additives with the precursor of g-C₃N₄. In comparison, post-functionalization of g-C₃N₄ has 40 extra advantages of introducing much more functional groups or dopants into g-C₃N₄ after the lattice is formed at elevated temperatures. However, the high chemical stability and bad solubility in common solvents of g-C₃N₄ constitute a vast barrier to post-modify g-C₃N₄ material.¹⁸ Great efforts have been made to enhance the photocatalytic activity of g-C₃N₄, such as doping,^{19–23} copolymerization,^{18,24} texturization,^{25,26} supermolecular assembly,^{27,28} surface heterojunction design.²⁹ Highly condensed g-C₃N₄ with fewer defects favors enhanced the photocatalytic performance by increasing the crystallinity and charge carrier mobility.³⁰ Therefore, it is urgent for us to obtain highly efficient g-C₃N₄ with enhanced crystallinity and charge carrier separation efficiency in a novel way.³¹ To date, various nanoarchitectural g-C₃N₄, ranging from one-dimensional nanorods and nanowires to two-dimensional nanosheets and three-dimensional mesoporous structures, have been designed by many methods and strategies, such as hard/soft template synthesis,^{32–34} solvothermal/molten-salt technology,^{35,36} *ods*,^{37,38} and supramolecular chemistry.^{27,39}

Transition-metal dichalcogenides (TMDs), especially the ones with atomic thickness, have been regarded as a new class of nanomaterials for fundamental studies and promising applications because of their special properties. TMDs can be metals, semiconductors, or insulators,^{40–42} exhibiting diverse properties. MoS₂ is one of the most promising semiconductors owing to its inherent and thickness-dependent band gap as well as its abundance in nature as molybdenite.⁴³ Moreover, bulk MoS₂ crystals can be exfoliated to single- or few-layer

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nanosheets, which exhibit unusual physical and electronic properties. Specifically, bulk MoS₂ is a semiconductor with narrow band gap of about 1.3 eV, while the isolated MoS₂ monolayer possesses a large band gap of 1.8–1.9 eV.⁴³

It is worth noting that the MoS₂ nanosheets,⁴⁴ as an electron acceptor, can efficiently increase the visible-light absorbance, charge separation, specific surface area and active sites for reaction, which result in an enhanced photocatalysis ability. MoS₂/g-C₃N₄ heterojunction photocatalyst has been synthesized, using basically layered self-assembly technology and the impregnation method.^{45–53} In this paper, a facile method, impregnation–calcination, was applied to synthesize crossed-layer-structure MoS₂/g-C₃N₄. The activities of as-prepared photocatalysts were evaluated by photodegradation of methyl orange (MO) under simulated solar light illumination. The as-fabricated MoS₂/g-C₃N₄ heterojunction photocatalyst exhibited enhanced photoreactivity compared with the pure g-C₃N₄.

2. Experimental section

2.1 Reagents

Dicyandiamide (C₂H₄N₄, CP), isopropanol (IPA, AR), sodium molybdate (Na₂MoO₄, CP), thiourea (CN₂H₄S, CP), disodium ethylenediaminetetraacetate dehydrate (EDTA-2Na, AR), 1,4-benzoquinone (BQ, AR), methyl orange (MO, AR), and other chemicals involved were purchased from Sinopharm Chemical Reagent Co., Ltd. (China) and used directly for experimental without further purifications. All aqueous solutions throughout were prepared with the deionized water.

2.2 Catalysts preparation

2.2.1 Preparation of bulk g-C₃N₄. Graphitic carbon nitride was synthesized using dicyandiamide. In a typical run, the precursor was put in a lidded high quality alumina crucible, then placed inside a tube furnace and heated at 5 °C minute^{−1}, and finally held at 550 °C for 4 hours in Ar flow. The resultant powders were then washed with water, HCl, and once again with water to remove all unreacted and potentially detrimental surface species. The products were denoted as g-C₃N₄.

2.2.2 Preparation of MoS₂ sheets. Bulk MoS₂ (BMS) was synthesized by the hydrothermal method. 242 mg sodium molybdate and 342.5 mg thiourea were dissolved in 60.0 mL distilled water and further ultrasonicated for 1 h, and then transferred into a Teflon-lined stainless steel autoclave. The autoclave was heated in the oven at 200 °C for 24 hours and cooled to room temperature naturally. The as-obtained product was washed with water and ethanol, and precipitated by centrifuge with a speed of 10 000 rpm. Then dried in an oven at 60 °C for 24 h. 1 g bulk MoS₂ powder was put into a 100 mL glass bottle and ultrasonicated for 48 h, then put the suspension 4 mg mL^{−1}.

2.2.3 Preparation of crossed-layer-structure MoS₂/g-C₃N₄ heterojunction photocatalyst. In a typical synthesis of MoS₂/g-C₃N₄ hybrid, 10 g of dicyandiamide and 0.5 (1, 2.5, 5, 12.5, 25) mL MoS₂ suspension were immersed into 50 mL aqueous solution. These were then mixed with stirring and

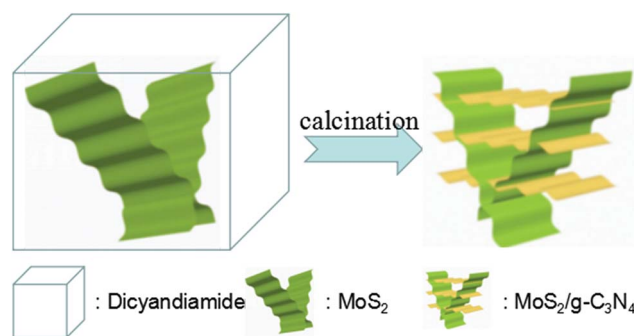
ultrasonication for 60 min as-prepared precursor was obtained after evaporation and drying in an oven at 60 °C for 24 h. Then calcination of these as-prepared precursor stabilized at 550 °C for 4 h with a ramp rate of 5 °C min^{−1} in Ar flow from room temperature, as shown in Scheme 1. The resultant powders were then washed with water, HCl, and once again with water to remove all unreacted and potentially detrimental surface species. The obtained samples were designated as MoS₂/g-C₃N₄-2, MoS₂/g-C₃N₄-4, MoS₂/g-C₃N₄-10, MoS₂/g-C₃N₄-20, MoS₂/g-C₃N₄-50 and MoS₂/g-C₃N₄-100 respectively.

2.3 Catalysts characterization

X-ray diffraction (XRD) of the samples was carried out on a Bruker AXS D8 X-ray diffractometer with a Cu-Kα X-ray source operating at 40 kV and 100 mA. The morphologies of the samples were observed using a scanning electron microscope (SEM, JEOL JSM-6490LV) and a transmission electron microscope (TEM, FEI Tecnai G2). X-ray photoelectron spectroscopic (XPS) measurements were made on an Escalab 250Xi system. UV-vis diffuse reflection spectra of the as-prepared products were carried out using an Evolution 220 UV-vis spectrophotometer (Thermo Fisher) from 200 to 800 nm. Fourier transform infrared (FT-IR) spectra of the samples were measured by a Nicolet 5700 Fourier transform infrared spectrometer. The photoluminescence spectra (PL) of the samples were obtained using a fluorescence spectrometer (Hitachi F-4500) at 293 K. The photocurrent curves and electrochemical impedance spectroscopy (EIS) plots were collected by a CHI660 electrochemical analyzer.

2.4 Photocatalytic experiments

The activity of the photocatalysts was evaluated *via* the photocatalytic degradation of MO under simulated solar light irradiation. In a typical experiment, 0.05 g photocatalyst was suspended in 100 mL 10 mg L^{−1} MO solution. The suspension was first dispersed by sonication for 30 min and stirred for 30 min in the dark to obtain adsorption–desorption equilibrium between the MO and the photocatalyst. The suspension was then stirred and irradiated under a 500 W Xe lamp. During the irradiation process, about 3 mL of suspension was taken from the reaction cell every 30 min and centrifuged to remove the photocatalyst. The absorbance of the MO solution in degradation was detected on TU-1900 UV-vis spectrophotometer.



Scheme 1 Schematic illustration for the preparation of crossed-layer-structure MoS₂/g-C₃N₄ heterojunction photocatalyst.



2.5 Electrochemical measurements

Photoelectrochemical measurements were performed in a three-electrode, single compartment quartz cell on an electrochemical station (CHI 660). Samples on ITO glass with an active area of *ca.* 1.0 cm² (1 mg of photocatalyst) were prepared as the working electrode. The platinum sheet and saturated calomel electrode (SCE) were served as the counter electrode and reference electrode, respectively. Besides, a bias voltage of 0.5 V was used for driving the photo-generated electrons transfer from the working electrode to the platinum electrode. The light source (300 W xenon lamp) with ultraviolet filter ($\lambda > 400$ nm) was mounted 10.0 cm away from the photoelectrochemical cell. A 0.50 M Na₂SO₄ aqueous solution worked as the electrolyte.

3. Results and discussion

The XRD patterns of the as-prepared pure g-C₃N₄, MoS₂, and MoS₂/g-C₃N₄ nanocomposites were shown in Fig. 1. These two peaks at 13.057° and 27.76° matched well with the (100) and (002) crystal planes of graphitic carbon nitride. This result

demonstrate that the synthesized samples were graphitic carbon nitride. The small angle peak at 13.057°, which corresponded to a *d*-spacing of 0.677 nm, was due to the in-plane structural packing motif. The strong peak at 27.76° was a characteristic interlayer stacking peak and corresponded to an interlayer distance of *d* = 0.321 nm, as shown in Fig. 1a. Existing two diffraction peaks at 12.91° and 14.17° corresponded to g-C₃N₄ (100) peak and MoS₂ (002) peak in MoS₂/g-C₃N₄-50 and MoS₂/g-C₃N₄-100, however no distinct diffraction peaks corresponding to other MoS₂ co-catalysts could be observed. This might be due to the small amount of MoS₂ contents, having small amount of MoS₂ contents in the surface of g-C₃N₄ and highly dispersion in the interior of polymeric g-C₃N₄ photocatalysts. The presence of MoS₂ in the MoS₂/g-C₃N₄ composite samples could be confirmed by TEM, SEM and XPS analyses, as discussed later. From the inset, the (002) peak of MoS₂ co-catalysts shifted to left comparing with pure g-C₃N₄.⁵¹ Moreover, the diffraction peaks at 14.0°, 33.4° and 58.7° were in good agreement with the (002), (100) and (110) planes of the hexagonal phase of MoS₂ in Fig. 1b.

The structural information of the as-developed g-C₃N₄ and MoS₂/g-C₃N₄ samples were confirmed by the FT-IR analysis (Fig. 2). FT-IR spectrum showed the presence of polar oxygen-containing functionalities at 1062 cm⁻¹ (C–O–C stretching) and 1205 cm⁻¹ (phenolic C–OH stretching). Further observation, the characteristic peaks of MoS₂/g-C₃N₄ were found to be almost identical to the pure g-C₃N₄, inferring that the impregnation of MoS₂ did not destroy the in-plane tri-s-triazine units. The MoS₂/g-C₃N₄ sample revealed almost similar characteristic features to the pure g-C₃N₄, verifying that the structural integrity of g-C₃N₄ remained intact after the incorporation with MoS₂. Several strong absorption bands in the range of 1200–1650 cm⁻¹ was originated from the skeletal stretching of C–N heterocycles with peaks positioned at 1632, 1573, 1423, 1329 and 1245 cm⁻¹, comprising both trigonal N–(C)₃ (full condensation) and bridging C–NH–C units (partial condensation). This exemplified the successful development of the extended C–N–C

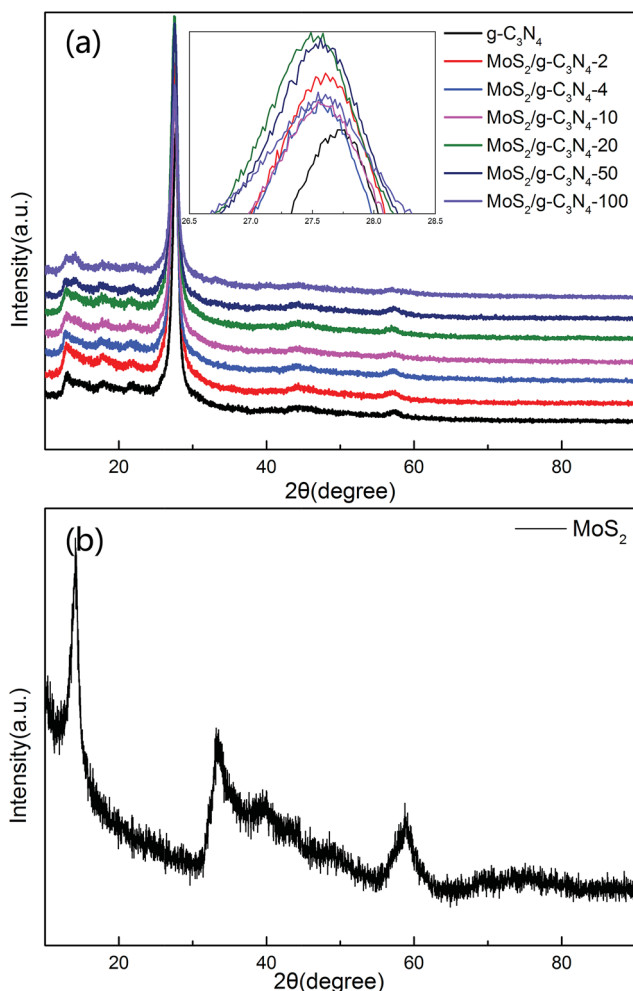


Fig. 1 XRD patterns of different photocatalyst: (a) pure g-C₃N₄ and a series of MoS₂/g-C₃N₄ (b) MoS₂.

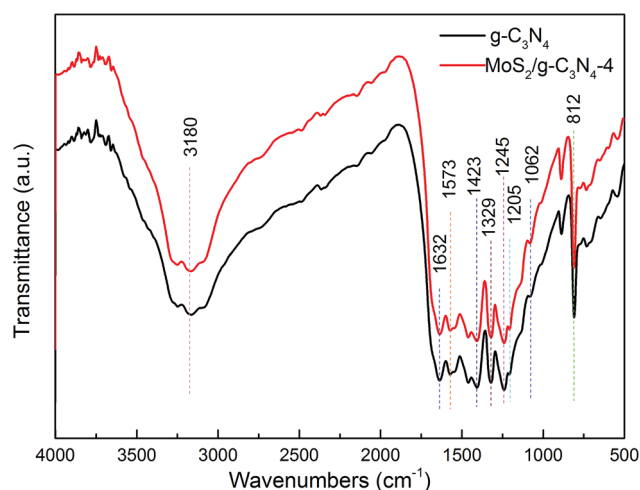


Fig. 2 FT-IR spectra of pure g-C₃N₄ and MoS₂/g-C₃N₄-4 heterojunction photocatalyst.



network. The broad peak ranging from 3000 to 3700 cm^{-1} was assigned to the N–H and O–H stretches due to the free amino groups and adsorbed hydroxyl species, respectively, whereas the sharp band at 812 cm^{-1} was derived from the breathing vibration of tri-s-triazine units.⁵⁴ The virtually identical X-ray diffraction patterns (Fig. 1) and FT-IR spectra (Fig. 2) of $\text{g-C}_3\text{N}_4$ and $\text{MoS}_2/\text{g-C}_3\text{N}_4$ reveal that loading with MoS_2 does not change the bulk structure of $\text{g-C}_3\text{N}_4$.

XPS of $\text{MoS}_2/\text{g-C}_3\text{N}_4$ samples were measured on an Escalab 250Xi system and shown in Fig. 3. However, the C/N atomic ratio increased from 0.77 for $\text{g-C}_3\text{N}_4$ to 0.84 for $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 (Fig. 3a). There were mainly two carbon species presented in the samples (Fig. 3b): one (284.6 eV) was sp^2 C–C bonds, and the other one (288.0 eV) was sp^2 -hybridized carbon in N-containing aromatic ring (N–C=N). The latter was considered as the major carbon species in C_3N_4 layer. The high resolution N1s spectra could be also deconvoluted into three different peaks at binding energies of 398.7, 400.2, 401.3 eV, respectively (Fig. 3c). These peaks could be ascribed to the sp^2 -hybridized nitrogen involved in triazine rings (C–N=C), the tertiary nitrogen N–(C)₃ groups, and the free amino groups (C–N–H), respectively. A weak O1s peak at 532.1 eV in the $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 was attributed to the adsorbed H_2O or CO_2 , which was a common phenomenon found in literatures (Fig. 3d).⁵⁵ For Mo3d spectra, two peaks, accredited to the doublet $\text{Mo}3\text{d}_{5/2}$ and $\text{Mo}3\text{d}_{3/2}$, were located at 229.4 and 232.5 eV (Fig. 3e). The other peak, corresponding to the $\text{S}2\text{p}_{3/2}$ orbital of divalent sulfide ions (S^{2-}), was observed at 162.3 eV (Fig. 3f). Those results indicate the existence of Mo^{4+}

and S^{2-} , with an atomic composition ratio for Mo and S of 1 : 2. Of course, existing two peaks in the Fig. 5C corresponding to $\text{S}2\text{p}_{3/2}$ and $\text{S}2\text{p}_{1/2}$ orbital of tetravalent sulphide ions (S^{4-}), were observed at 167.5 and 168.6 eV.⁵⁶ This is contributed to high-temperature calcination, which make divalent sulfide ions (S^{2-}) be reduced to tetravalent sulfide ions (S^{4-}), and produce a lot sulfide vacancy, which lead to great improvement of catalyst activity.

Transmission electron microscopy (TEM) image were showed in Fig. 4. Compared with pure $\text{g-C}_3\text{N}_4$ (Fig. 4c), the as-prepared $\text{MoS}_2/\text{g-C}_3\text{N}_4$ samples with laminar morphology exhibited nearly transparent feature with black lines and black cycles, indicating its crossed-layer-structure (Fig. 4a and b). Transparent layer structure of MoS_2 was observed (Fig. 4d), indicating that the black lines and black cycles in $\text{MoS}_2/\text{g-C}_3\text{N}_4$ samples (Fig. 4a and b) were MoS_2 . The morphology of crossed-layer-structure $\text{MoS}_2/\text{g-C}_3\text{N}_4$ was also investigated *via* scanning electron microscopy (SEM). As shown in Fig. 5a and b, crossed-layer-structure $\text{MoS}_2/\text{g-C}_3\text{N}_4$ samples still maintained loose and irregular cross-like 3D morphology, although a great portion of $\text{g-C}_3\text{N}_4$ nanosheets was stacked. Its morphology was quite different from that of the pure $\text{g-C}_3\text{N}_4$ with a typical layer structure stacked layer by layer (Fig. 5c) and MoS_2 with sheet structure (Fig. 5d). To further verify the crossed-layer-structure, EDX elements mappings were carried out and the results were shown in Fig. 6. Elements mapping of $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 reveals that the sample mainly contains five elements (C, N, O, S and Mo), which is coincident with the results from XPS (Fig. 3). Of course, the results also confirmed further the existence of the crossed-layer-structure.

The BET surface areas and porous structures of the photocatalysts were investigated by nitrogen adsorption–desorption. Fig. 7a and b showed the nitrogen adsorption–desorption isotherms and the corresponding pore-size distribution curves of pure $\text{g-C}_3\text{N}_4$ and $\text{MoS}_2/\text{g-C}_3\text{N}_4$ heterojunction catalysts ($\text{MoS}_2/\text{g-C}_3\text{N}_4$ -2, $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 and $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -50). It was obvious that the nitrogen adsorption–desorption isotherms for

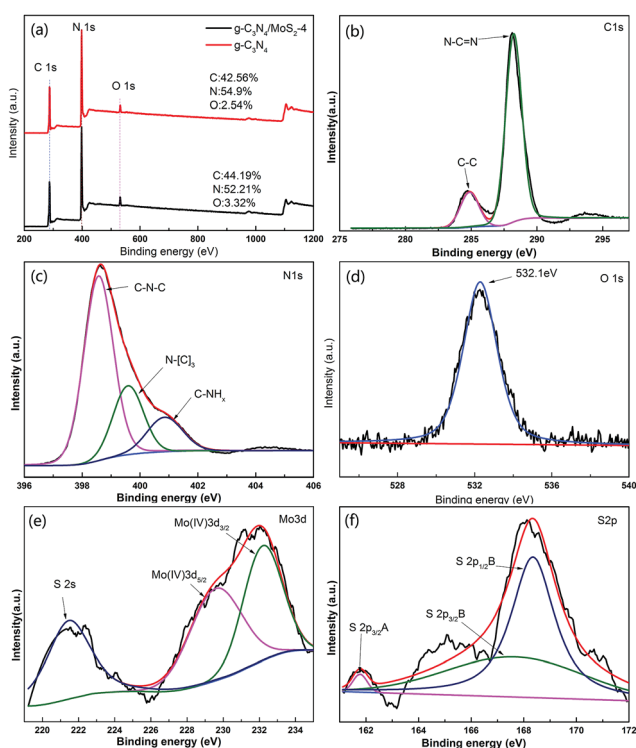


Fig. 3 XPS spectra of as-fabricated photocatalysts: (a) survey of $\text{g-C}_3\text{N}_4$ and $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 and (b) C1s; (c) N1s; (d) O1s; (e) S2p; (f) Mo3d of $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4.

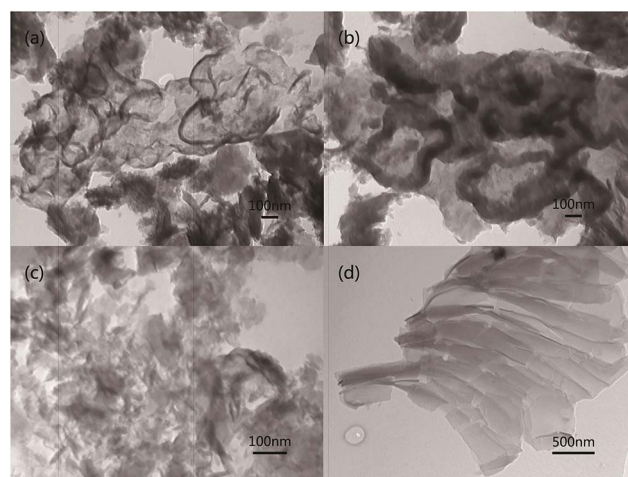


Fig. 4 Typical TEM images of (a) $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4, (b) $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -100, (c) $\text{g-C}_3\text{N}_4$, (d) MoS_2 samples.



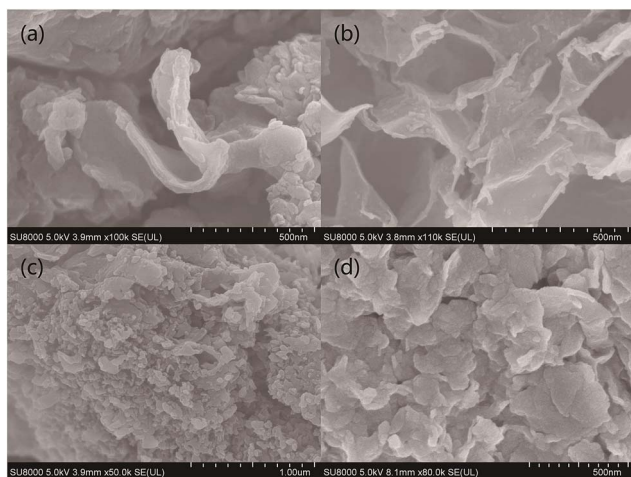


Fig. 5 Typical SEM images of (a) $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4, (b) $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -100, (c) pure $\text{g-C}_3\text{N}_4$ and (d) MoS_2 samples.

pure $\text{g-C}_3\text{N}_4$ and $\text{MoS}_2/\text{g-C}_3\text{N}_4$ heterojunction catalysts belonged to type IV, indicating the presence of macropores. The increase of the surface areas was accompanied by the increase of the pore volumes, resulting from the increased size of the generated pores as suggested by the slight shift of the hysteresis onset in the corresponding nitrogen sorption isotherms to higher P/P_0 as well as by the results of pore size analysis (Fig. 7a and b). Pure $\text{g-C}_3\text{N}_4$ catalyst had a Brunauer–Emmett–Teller (BET) surface area of $34.38 \text{ m}^2 \text{ g}^{-1}$ and a pore volume of $0.077 \text{ cm}^3 \text{ g}^{-1}$. While the BET surface areas and pore volumes of $\text{MoS}_2/\text{g-C}_3\text{N}_4$ samples

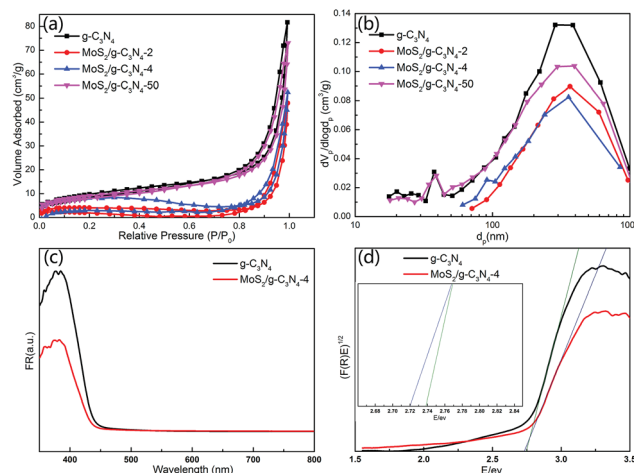


Fig. 7 (a) N_2 adsorption isotherms and (b) pore size distribution of the $\text{g-C}_3\text{N}_4$ and $\text{MoS}_2/\text{g-C}_3\text{N}_4$, (c) UV-vis spectra of $\text{g-C}_3\text{N}_4$ and $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 composites. (d) The plot of $(F(R)E)^{1/2}$ versus energy (E) for the band gap energy of $\text{g-C}_3\text{N}_4$ and $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4.

were less than pure $\text{g-C}_3\text{N}_4$. For $\text{MoS}_2/\text{g-C}_3\text{N}_4$ samples, with the mass of MoS_2 increasing, the BET surface areas and pore volume were increasing (Table 1).

The UV-Vis diffuse reflectance spectra (DRS) and the band gap values calculated by plots of $(F(R)E)^{1/2}$ versus photo energy of $\text{g-C}_3\text{N}_4$ and $\text{MoS}_2/\text{g-C}_3\text{N}_4$ were shown in Fig. 7c and d. The band gap energy of $\text{g-C}_3\text{N}_4$ in the onset is about 2.75 eV, corresponding to an absorption edge of 450 nm. After hybridization with MoS_2 , the band gap of $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 was about 2.72 eV, with an absorption edge of 455 nm. The composite photocatalyst can improve the utilization of the visible light.

The charge carrier separation and recombination rates of the photoexcited carriers were investigated using room temperature photoluminescence spectra with an excitation wavelength of 431 nm. As shown in Fig. 8, $\text{g-C}_3\text{N}_4$ exhibited a broad emission peak that was centered at 450 nm due to the band-band PL phenomenon with the energy of light, which was approximately equal to the bandgap energy of $\text{g-C}_3\text{N}_4$. The emission peak of $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 shifted to ca. 455 nm, which was consistent with DRS results. The PL intensity for $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 decreased significantly compared to that of $\text{g-C}_3\text{N}_4$. In general, a decrease in the PL intensity indicates a suppressed electron–hole pair recombination, which makes $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 to generate more photoelectrons and holes to participate in the photocatalytic reaction. This may be because the heterojunction formed at the interface and interior between $\text{g-C}_3\text{N}_4$ and MoS_2 with a high rate

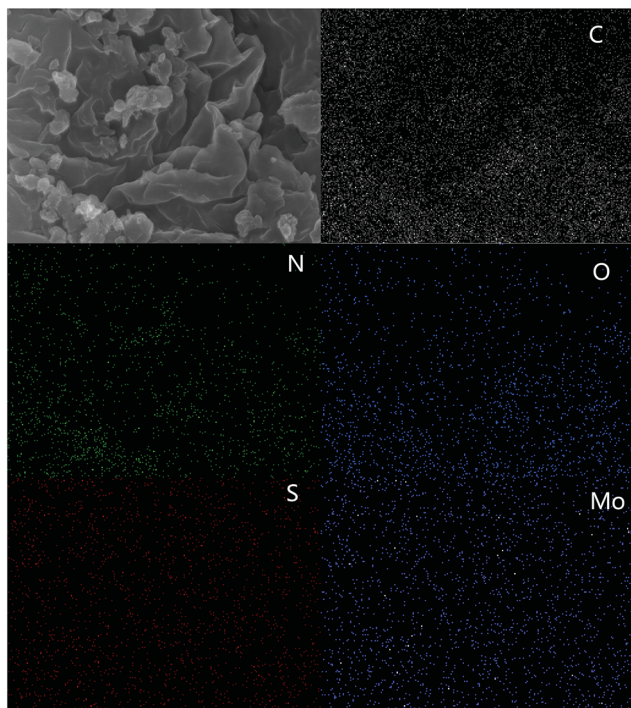


Fig. 6 SEM images and corresponding mapping images of $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4.

Table 1 BET specific surface area and pore volume of the $\text{g-C}_3\text{N}_4$ and $\text{MoS}_2/\text{g-C}_3\text{N}_4$ samples

Samples	$\text{g-C}_3\text{N}_4$	$\text{MoS}_2/\text{g-C}_3\text{N}_4$ -2	$\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4	$\text{MoS}_2/\text{g-C}_3\text{N}_4$ -50
BET ($\text{m}^2 \text{ g}^{-1}$)	34.3807	11.3649	24.527	31.109
Pore volume ($\text{cm}^3 \text{ g}^{-1}$)	0.0778	0.0368	0.0465	0.0717



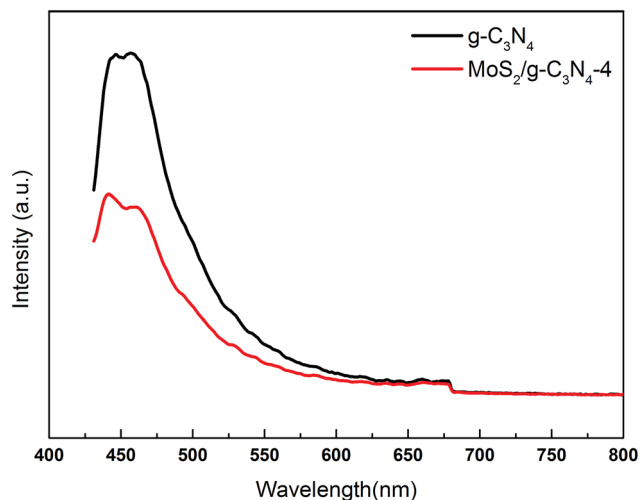


Fig. 8 PL spectra of pure $g\text{-C}_3\text{N}_4$ and $\text{MoS}_2/g\text{-C}_3\text{N}_4\text{-4}$ composites under 431 nm excitation at room temperature.

of carrier mobility can restrain the recombination of photo-generated charge effectively and accelerate charge transport.

To gain deeper insights into the charge transport behavior in the $\text{MoS}_2/g\text{-C}_3\text{N}_4$ system, we conducted electrochemical impedance spectroscopy (EIS) measurements (Fig. 9). In the Nyquist diagram, the radius of each arc is associated with the charge-transfer process at the corresponding electrode/electrolyte interface with a smaller radius corresponding with a lower charge-transfer resistance.^{49,56} The $\text{MoS}_2/g\text{-C}_3\text{N}_4\text{-4}$ exhibited the smallest charge transfer resistance among all $g\text{-C}_3\text{N}_4$ -based electrodes under visible light irradiation, suggesting that effective shuttling of charges between the electrode and the electrolyte, and faster interfacial charge transfer occurred at the composite interface and interior owing to the formation of the crossed-layer-structure.

Semiconductors exhibit unique photoelectric properties owing to their essential band-gap structure, which provides

a simple and economical light-to-electric conversion approach for various energy-related applications. Separation of electrons and holes plays a significant role in the photocatalytic reaction, and the photocurrent derives from electrons stimulated from the valence band to the conduction band under visible-light irradiation. Therefore, a higher photocurrent response indicates better separation efficiency of electrons and holes, which boosts the photocatalytic activity of the photocatalysts.⁵⁷ Fig. 10 displayed the transient photocurrent response of as-fabricated product printed on indium tin oxide (ITO) glass plates in a 0.5 M Na_2SO_4 aqueous solution under 300 W Xe lamp light irradiation ($\lambda > 400$ nm). The transient photocurrents of the samples were measured during repeated ON/OFF illumination cycles at 0.5 V. All of the samples exhibit prompt and reproducible photocurrent responses on each illumination. When the irradiation was interrupted, the photocurrent rapidly dropped to almost zero (steady-state value), and the photocurrent reverted to the original value once light was switched back on again. The photocurrent density of the $\text{MoS}_2/g\text{-C}_3\text{N}_4\text{-4}$ is about 1.93 times higher than that of the pure $g\text{-C}_3\text{N}_4$. In addition, the transient photocurrent is widely regarded as the most efficient evidence to characterize charge separation.⁵⁸ The unique crossed-layer-structure can further shorten the photo-electron transport distance, thus facilitating fast electron transfer across the crossed-layer-structure. These results suggest that the enhanced light harvesting, efficient separation of photogenerated electron-hole pairs and the crossed-layer-structure of the $\text{MoS}_2/g\text{-C}_3\text{N}_4$ have a significant role in improving the overall photoelectrochemical performance.

The photocatalytic activities of the as-prepared $g\text{-C}_3\text{N}_4$, and $\text{MoS}_2/g\text{-C}_3\text{N}_4$ were evaluated by the degradation of MO in aqueous solution under visible light irradiation. We studied the influence of the MoS_2 amount in $\text{MoS}_2/g\text{-C}_3\text{N}_4$ on the photocatalytic activity under the same conditions. As shown in Fig. 11, the removal rate of MO using $\text{MoS}_2/g\text{-C}_3\text{N}_4$ as the photocatalyst was higher than that of pure $g\text{-C}_3\text{N}_4$, and it improved gradually with the increase of the MoS_2 amount. When the

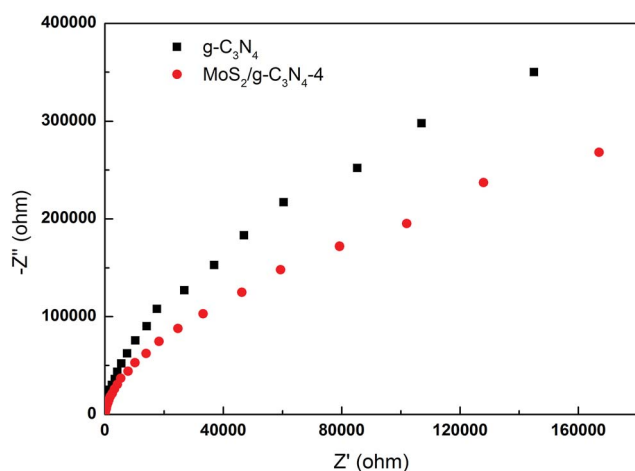


Fig. 9 Electrochemical impedance spectroscopy of the $g\text{-C}_3\text{N}_4$ and $\text{MoS}_2/g\text{-C}_3\text{N}_4\text{-4}$ samples.

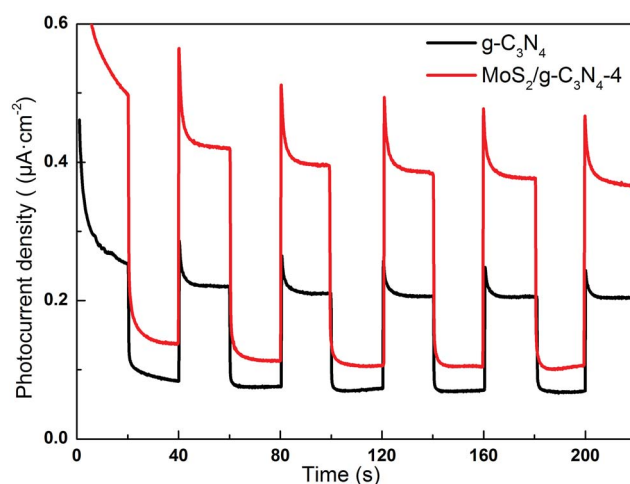


Fig. 10 Transient photocurrent response for the $g\text{-C}_3\text{N}_4$ and $\text{MoS}_2/g\text{-C}_3\text{N}_4\text{-4}$ sample.



percent of MoS₂ reached 0.16% (MoS₂/g-C₃N₄-4), it exhibited the highest photocatalytic activity. However, photocatalytic activity of MoS₂/g-C₃N₄-20 (0.8%) was significantly lower than that of MoS₂/g-C₃N₄-4 (0.16%). The reason might be that the too many active sites of g-C₃N₄ were covered by MoS₂, leading to weaken the absorption of visible light by g-C₃N₄, and causing the decrease of photocatalytic activity. Yet according to the results of BET analysis, surface areas and pore volumes were not main reason for enhancing photocatalytic degradation activity. We inferred that the enhanced activities were due to the synergistic effect between g-C₃N₄ and MoS₂. The optimum photocatalytic degradation efficiency of MO was 68% for MoS₂/g-C₃N₄-4 (0.16%), which is much higher than that of g-C₃N₄. In other words, it demonstrated 3.4 times higher performance than g-C₃N₄. Of course, we also tested the visible light activity for degradation of colorless pollutant (phenol) in Fig. S1.† Compared with degradation MO under stimulated solar light in Fig. 11, we observed that the tendency was consistent and MoS₂/g-C₃N₄-4 showed optimal activity among the MoS₂/g-C₃N₄ heterojunction catalysts. The result of photocatalytic degradation of phenol by thermal treatment g-C₃N₄ was added in the Fig. S2,† there were no obvious change in degradation phenol under visible light, so in the photocatalytic degradation phenol process, the thermal treatment could not promote the photocatalytic activity of g-C₃N₄. In summary, the high performance was attributed to the enhanced light harvesting efficient separation of photogenerated electron-hole pairs, and the crossed-layer-structure of the MoS₂/g-C₃N₄.

In order to confirm the main active species for the photocatalytic degradation of MO over MoS₂/g-C₃N₄, the scavengers BQ, disodium EDTA and IPA were added to quench the possible active species $\cdot\text{O}_2^-$, hole (h^+) and $\cdot\text{OH}$, respectively.^{41–44} As shown in Fig. 12, when disodium EDTA was added, the removal rate of MO had no obvious decrease, implying that h^+ did not dominate the photocatalytic reaction with MoS₂/g-C₃N₄. However, the dramatic decline of MO removal was achieved in the presence of BQ and IPA, suggesting that $\cdot\text{O}_2^-$ and $\cdot\text{OH}$ were

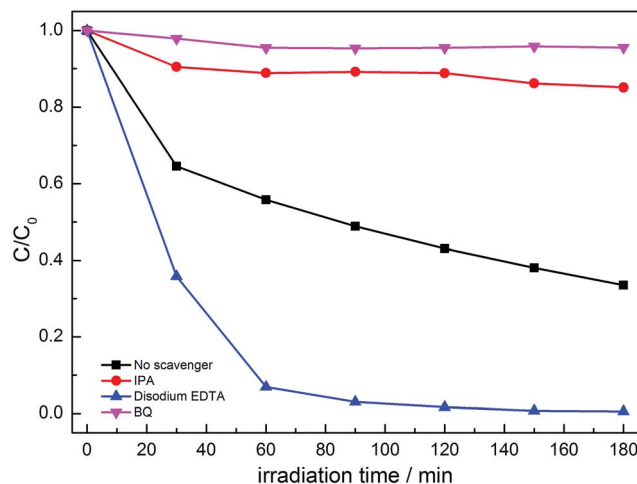


Fig. 12 Photocatalytic performances for the degradation of MO over MoS₂/g-C₃N₄-4 composite with different sacrificial agents under simulated solar light irradiation.

the main active species. According to the above results, we inferred that the enhanced activities stemmed from the synergistic effect of $\cdot\text{O}_2^-$ and $\cdot\text{OH}$ active species between g-C₃N₄ and MoS₂.

The photocatalytic mechanisms are illustrated in Fig. 13. The photoexcited electrons would transfer from g-C₃N₄ to MoS₂ due to the lower CB positions,^{53,58} and the separated electrons on the surface of MoS₂ would combine with adsorbed O₂ to produce $\cdot\text{O}_2^-$ radicals (the presence of $\cdot\text{O}_2^-$ was confirmed by previous report⁵⁹). Subsequently, it will combine with H⁺ to produce H₂O₂ which finally decomposes into hydroxyl radicals.^{60,61} At the same time, the accumulated holes on the surface of g-C₃N₄ would oxidize H₂O to $\cdot\text{OH}$, then $\cdot\text{OH}$ would oxidize dye molecules to H₂O/CO₂. In Fig. 11, disodium EDTA, as a sacrificial agent of hole, was added to the reaction system, with the holes decreasing, meanwhile, the balance moves to the direction which can produce holes and electrons. The mentioned factor would produce a large amount of electrons and improve the separation efficiency of photogenerated

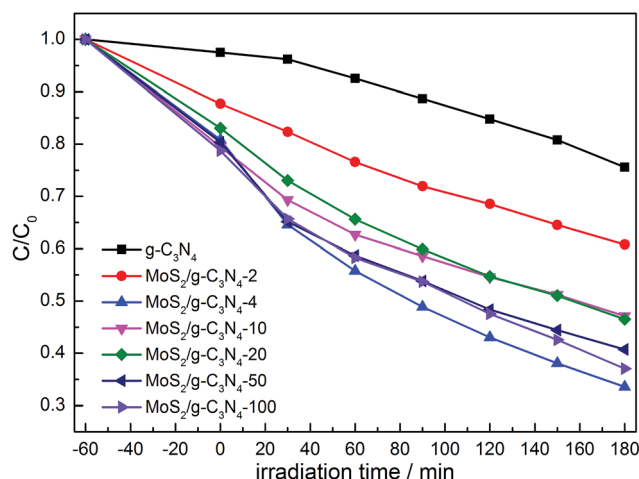


Fig. 11 Photocatalytic degradation of MO by g-C₃N₄ and various MoS₂/g-C₃N₄ samples under simulated solar light.

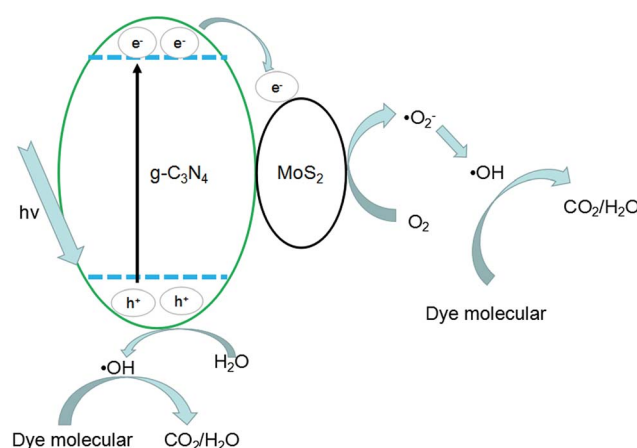


Fig. 13 Photocatalytic mechanism of MoS₂/g-C₃N₄ heterostructures.



electron-hole pairs. In the reaction of dye degradation, the addition of disodium EDTA made its reaction rate increasing greatly. The observed MO degradation was more than 90% in an hour. When IPA and BQ were added into the reaction system, the $\cdot\text{OH}$ and $\cdot\text{O}_2^-$ were captured, which led to active component of dye degradation sharply reducing and we could observe the degradation ability had fallen dramatically. Compared with pure $\text{g-C}_3\text{N}_4$, the $\text{MoS}_2/\text{g-C}_3\text{N}_4$, the $\text{MoS}_2/\text{g-C}_3\text{N}_4$ heterostructure had extended the lifetime of separated electron-hole pairs, resulting in the improvement of photocatalytic degradation efficiency.

4. Conclusions

We have demonstrated a novel method to prepare crossed-layer-structure $\text{MoS}_2/\text{g-C}_3\text{N}_4$ heterojunction photocatalyst by impregnation-calcination, which have been evidenced by TEM, SEM, XRD, XPS, IR and UV-vis DRS analysis. Under simulated solar light irradiation for 3 h, the optimum photocatalytic degradation efficiency of MO was 68% for $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 (0.16%), which is much higher than that of $\text{g-C}_3\text{N}_4$. In other words, it demonstrated 3.4 times higher performance than $\text{g-C}_3\text{N}_4$. Of course, $\text{MoS}_2/\text{g-C}_3\text{N}_4$ -4 also showed optimal activity in phenol degradation under visible light. The high performance was attributed to the enhanced light harvesting efficient separation of photogenerated electron-hole pairs and the crossed-layer-structure of the $\text{MoS}_2/\text{g-C}_3\text{N}_4$, which play a significant role in improving the overall photocatalytic performance.

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